NSN 5961-01-325-6167

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-6167 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.300 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.060 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method:** Terminal **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse voltage, instantaneous **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: